

BYT 12PI-1000

FAST RECOVERY RECTIFIER DIODE

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- INSULATED: Capacitance 7pF



SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	1000	V	
V _{RSM}	Non Repetitive Peak Reverse Voltage	1000	V	
I _{FRM}	Repetive Peak Forward Current	150	А	
I _{F (RMS)}	RMS Forward Current	25	А	
I _{F (AV)}	Average Forward Current $T_c = 50^{\circ}C$ $\delta = 0.5$		12	A
I _{FSM}	Surge non Repetitive Forward Currenttp = 10msSinusoidal		75	A
Р	Power Dissipation $T_c = 50^{\circ}C$		25	W
T _{stg} Tj	Storage and Junction Temperature Range	- 40 to + 150 - 40 to + 150	°C	

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
R _{th (j - c)}	Junction-case	4	°C/W

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I _R	$T_j = 25^{\circ}C$	$V_{R} = V_{RRM}$			50	μΑ
	$T_j = 100^{\circ}C$				2.5	mA
V _F	$T_j = 25^{\circ}C$	I _F = 12A			1.9	V
	$T_j = 100^{\circ}C$				1.8	r

RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Тур.	Max.	Unit	
t _{rr}	$T_j = 25^{\circ}C$	I _F = 1A	di _F /dt = - 15A/µs	$V_R = 30V$			155	ns
		I _F = 0.5A	I _R = 1A	$I_{rr} = 0.25A$			65	

TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Тур.	Max.	Unit
t _{IRM}	di _F /dt = - 50A/µs	V _{CC} = 200 V I _F = 12A			200	ns
	di _F /dt = - 100A/µs	L _p ≤ 0.05μH T _j = 100°C See figure 11		120		
I _{RM}	di _F /dt = -50A/µs				7.8	А
	di _F /dt = - 100A/µs			9		

TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Conditions			Min.	Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	T _j = 100°C di _F /dt = - 12A/μs	V _{CC} = 200V L _p = 12μH	I _F = I _{F (AV)} See figure 12			4.5	

To evaluate the conduction losses use the following equations: $V_F = 1.47 + 0.026 I_F$ $P = 1.47 \times IF_{(AV)} + 0.026 I_F^{2}_{(RMS)}$

Figure 1. Low frequency power losses versus average current







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Figure 3. Non repetitive peak surge current versus overload duration







Figure 7. Recovery time versus di_F/d_{t-}



Figure 4. Thermal impedance versus pulse width



Figure 6. Recovery charge versus di_F/d_{t-}



Figure 8. Peak reverse current versus di_F/d_{t-}



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Figure 9. Peak forward voltage versus di_F/dt-



Figure 11. Turn-off switching characteristics (without series inductance).



Figure 12. Turn-off switching characteristics (with series inductance)



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PACKAGE MECHANICAL DATA :





- Marking: type number
- Cooling method: by conduction (method C)
- Weight : 1.86g
- Recommended torque value : 80cm. N
- Maximum torque value : 100cm. N

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